## **Supporting Information**

## Perovskite/Organic Hybrid Tandem Light-Emitting Diodes with External Quantum Efficiency Over 40%

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**Fig. S1.** (a) Power efficiency-current density (*PE-J*) curves of 40 nm thick TAPC-based POTLEDs with x nm TPBi (x = 20, 30, 40, 50, respectively) and (b) *PE-J* curves of 30 nm thick TPBi-based POTLEDs with y nm TAPC (y = 30, 40, 50, 60, respectively).



**Fig. S2**. (a) Electroluminescence (EL) spectra of PeLED, OLED and POTLED. (b) EL spectra of 30 nm thick TPBi and 50 nm thick TAPC based POTLED under different applied voltages. (c-d) CIE coordinates of the POTLED devices based on different TPBi and TAPC thicknesses under different applied voltages.



**Fig. S3.** Color gamut of OLED, PeLED, and POTLED with fixed blue and red CIE coordinates with the NTSC standards in a CIE 1931 chromaticity diagram.



**Fig. S4.** (a) Current density and luminance versus voltage (*J-V-L*) plots of POTLEDs with x nm Bphen:Yb (x = 5, 10, 20, respectively) and (b) corresponding current efficiency-current density (*CE-J*) curves of the devices and (c) corresponding external quantum efficiency-current density (*EQE-J*) curves of the devices.

TPBi <sup>a</sup>	V <sub>on</sub> <sup>b</sup>	CE <sub>max</sub>	<b>EQE</b> <sub>max</sub>	<b>PE</b> <sub>max</sub>	L <sub>max</sub>	CIE °
(nm)	<b>(V)</b>	(cd A <sup>-1</sup> )	(%)	(lm W <sup>-1</sup> )	(cd m <sup>-2</sup> )	(x, y)
20.0	5.2	110.6	33.1	56.1	20030.0	(0.246, 0.641)
30.0	5.4	130.3	37.8	68.7	36890.0	(0.256, 0.642)
40.0	6.8	117.9	34.1	48.0	31180.0	(0.271, 0.629)
50.0	7.2	110.6	32.3	42.0	30660.0	(0.274, 0.625)

Table S1. Performance of POTLED devices with different TPBi thicknesses.

<sup>a</sup> POTLED devices with the TAPC thickness of 40 nm; <sup>b</sup> the voltage at the luminance of 1 cd m<sup>-2</sup>; <sup>c</sup> Commission International de I'Eclairage at about1000 cd m<sup>-2</sup>.

TAPC a	V <sub>on</sub> <sup>b</sup>	CE <sub>max</sub>	EQE <sub>max</sub>	PE <sub>max</sub>	L <sub>max</sub>	CIE °
(nm)	<b>(V)</b>	(cd A <sup>-1</sup> )	(%)	(lm W <sup>-1</sup> )	(cd m <sup>-2</sup> )	(x, y)
30.0	5.4	118.3	35.1	61.5	37690.0	(0.249, 0.638)
40.0	5.4	135.4	39.0	70.2	35450.0	(0.261, 0.642)
50.0	5.4	144.2	41.1	75.0	32630.0	(0.280, 0.635)
60.0	5.4	116.3	33.3	58.9	29790.0	(0.289, 0.629)

**Table S2.** Performance of POTLED devices with different TAPC thicknesses.

<sup>a</sup> POTLED devices with the TPBi thickness of 30 nm; <sup>b</sup> the voltage at the luminance of 1 cd m<sup>-2</sup>; <sup>c</sup> Commission International de I'Eclairage at about1000 cd m<sup>-2</sup>.



**Fig. S5.** (a) *CE-J*, and (b) *EQE-J* plots of the tandem OLED device. (c) EL spectra of the OLED tandem device under different applied voltages. (d) *PE-J* curve of the tandem OLED device.



Fig. S6. Lifetime of tandem OLED at the initial brightness of  $100 \text{ cd m}^{-2}$ .



Fig. S7. Lifetime of PeLED at the initial brightness of  $100 \text{ cd m}^{-2}$ .